Amendments to the Claims:

The following listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Previously Presented) A photochemical hole burning medium, comprising a material in which a rare earth complex and a reducing agent are dispersed in a solid matrix; wherein

the photochemical hole burning medium is used at low temperatures; and said rare earth complex is at least one complex selected from the group consisting of a europium (III) crown ether complex, a europium (III) polyether complex, and a europium (III) cryptand complex.

- 2. (Canceled)
- 3. (Previously Presented) The photochemical hole burning medium set forth in claim 1, wherein said rare earth complex and said reducing agent constitute an electron-donating composite compound.
- 4. (Original) The photochemical hole burning medium set forth in claim 3, wherein said electron-donating composite compound is a silane compound or a disilazane compound.
- 5. (Previously Presented) The photochemical hole burning medium set forth in claim 4, wherein said silane compound or the disilazane compound is a hexaalkyl disilazane represented by hexamethyl disilane or a hexamethyldisilazane.
- 6. (Original) The photochemical hole burning medium set forth in claim 3, wherein said electron-donating composite compound is an organic tin compound.
 - 7. (Canceled)
 - 8. (Canceled)

9. (Currently Amended) The photochemical hole burning medium set forth in
elaim 6A photochemical hole burning medium, comprising a material in which a rare earth
complex and a reducing agent are dispersed in a solid matrix; wherein
the photochemical hole burning medium is used at low temperatures; and
said rare earth complex is at least one complex selected from the group
consisting of a europium (III) crown ether complex, a europium (III) polyether complex, and a
europium (III) cryptand complex,
wherein said electron-donating composite compound is an organic tin
compound wherein said organic tin compound is a compound represented by RSnSnR in
which R is an alkyl group or an aryl group.

- 10. (Canceled)
- 11. (Canceled)
- 12. (Previously Presented) The photochemical hole burning medium set forth in claim 1, wherein said solid matrix is at least one glass-forming compound selected from the group consisting of silica, germanium oxide, boron oxide, phosphorous pentaoxide and tellurium oxide.
- 13. (Original) The photochemical hole burning medium set forth in claim 3, wherein said solid matrix is at least one glass-forming compound selected from the group consisting of silica, germanium oxide, boron oxide, phosphorus pentaoxide and tellurium oxide.
- 14. (Original) The photochemical hole burning medium set forth in claim 4, wherein said solid matrix is at least one glass-forming compound selected from the group consisting of silica, germanium oxide, boron oxide, phosphorus pentaoxide and tellurium oxide.

- 15. (Original) The photochemical hole burning medium set forth in claim 5, wherein said solid matrix is at least one glass-forming compound selected from the group consisting of silica, germanium oxide, boron oxide, phosphorus pentaoxide and tellurium oxide.
- 16. (Original) The photochemical hole burning medium set forth in claim 6, wherein said solid matrix is at least one glass-forming compound selected from the group consisting of silica, germanium oxide, boron oxide, phosphorus pentaoxide and tellurium oxide.
 - 17. (Canceled)
 - 18. (Canceled)
- 19. (Original) The photochemical hole burning medium set forth in claim 9, wherein said solid matrix is at least one glass-forming compound selected from the group consisting of silica, germanium oxide, boron oxide, phosphorus pentaoxide and tellurium oxide.
 - 20. (Canceled)
 - 21. (Canceled)
- 22. (Original) The photochemical hole burning medium set forth in claim 12, wherein at least one compound selected from the group consisting of Al₂O₃, Ga₂O₃, In₂O₃, TiO₂, ZrO₂, Nb₂O₅ and Ta₂O₅ is contained in said solid matrix.
- 23. (Original) The photochemical hole burning medium set forth in claim 13, wherein at least one compound selected from the group consisting of Al₂O₃, Ga₂O₃, In₂O₃, TiO₂, ZrO₂, Nb₂O₅ and Ta₂O₅ is contained in said solid matrix.
- 24. (Original) The photochemical hole burning medium set forth in claim 14, wherein at least one compound selected from the group consisting of Al₂O₃, Ga₂O₃, In₂O₃, TiO₂, ZrO₂, Nb₂O₅ and Ta₂O₅ is contained in said solid matrix.

- 25. (Original) The photochemical hole burning medium set forth in claim 15, wherein at least one compound selected from the group consisting of Al₂O₃, Ga₂O₃, In₂O₃, TiO₂, ZrO₂, Nb₂O₅ and Ta₂O₅ is contained in said solid matrix.
- 26. (Original) The photochemical hole burning medium set forth in claim 16, wherein at least one compound selected from the group consisting of Al₂O₃, Ga₂O₃, In₂O₃, TiO₂, ZrO₂, Nb₂O₅ and Ta₂O₅ is contained in said solid matrix.
 - 27. (Canceled)
 - 28. (Canceled)
- 29. (Original) The photochemical hole burning medium set forth in claim 19, wherein at least one compound selected from the group consisting of Al₂O₃, Ga₂O₃, In₂O₃, TiO₂, ZrO₂, Nb₂O₅ and Ta₂O₅ is contained in said solid matrix.
 - 30. (Canceled)
 - 31. (Canceled)
- 32. (Original) The photochemical hole burning medium set forth in claim 1, wherein the reducing agent has an oxidation/reduction potential of not more than 1 V.
 - 33. (Canceled)
- 34. (Original) The photochemical hole burning medium set forth in claim 3, wherein the reducing agent has an oxidation/reduction potential of not more than 1 V.
- 35. (Original) The photochemical hole burning medium set forth in claim 4, wherein the reducing agent has an oxidation/reduction potential of not more than 1 V.
- 36. (Original) The photochemical hole burning medium set forth in claim 5, wherein the reducing agent has an oxidation/reduction potential of not more than 1 V.
- 37. (Original) The photochemical hole burning medium set forth in claim 6, wherein the reducing agent has an oxidation/reduction potential of not more than 1 V.
 - 38. (Canceled)

- 39. (Canceled)
- 40. (Original) The photochemical hole burning medium set forth in claim 9, wherein the reducing agent has an oxidation/reduction potential of not more than 1 V.
 - 41. (Canceled)
 - 42. (Canceled)